Ordering number : ENN2973



ON Semiconductor DATA SHEET

2SA1699—PNP Epitaxial Planar Silicon Transistors

High-Voltage Driver Applications

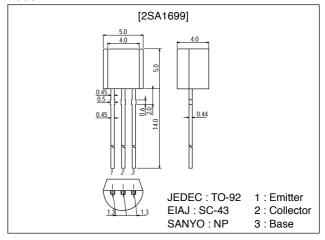
Features

- · High breakdown voltage.
- · Adoption of MBIT process.
- · Excellent hFE linearity.

Package Dimensions

unit:mm

2003B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		-400	V
Collector-to-Emitter Voltage	V _{CEO}		-400	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	ΙC		-200	mA
Colletor Current (Pulse)	I _{CP}		-400	mA
Collector Dissipation	PC		600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
raiametei			min	typ	max	Offic
Collector Cutoff Current	I _{CBO}	V _{CB} =-300V, I _E =0			-0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =-4V, I _C =0			-0.1	μΑ
DC Current Gain	hFE	V _{CE} =-10V, I _C =-50mA	60*		200*	
Gain-Bandwidth Product	fT	V _{CE} =-30V, I _C =-10mA		70		MHz

 $[\]mbox{\ast}$: The 2SA1699 is classified by 50mA \mbox{h}_{FE} as follows :

 Rank
 D
 E

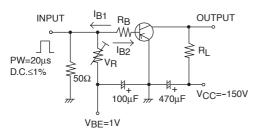
 hFE
 60 to 120
 100 to 200

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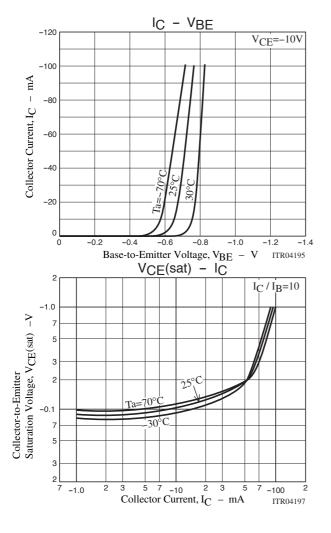
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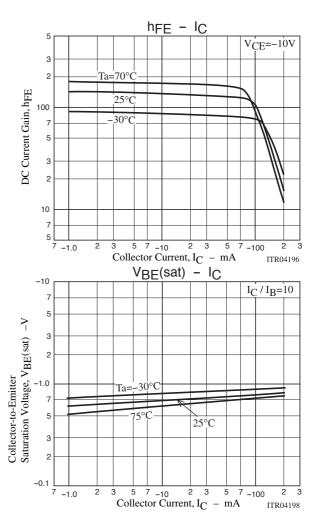
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =-50mA, I _B =-5mA			-0.8	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =-50mA, I _B =-5mA			-1.0	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	$I_{C}=-10\mu A, I_{E}=0$	-400			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =-1mA, R _{BE} =∞	-400			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =-10μA, I _C =0	-5			٧
Collector Output Capacitance	C _{ob}	V _{CB} =-30V, f=1MHz		5		pF
Reverse Trarnsfer Capacitance	C _{re}	V _{CB} =–30V, f=1MHz		4		pF
Turn-ON Time	t _{on}	See specified Test Circuit		0.25		μs
Turn-OFF Time	toff	See specified Test Circuit		5		μs

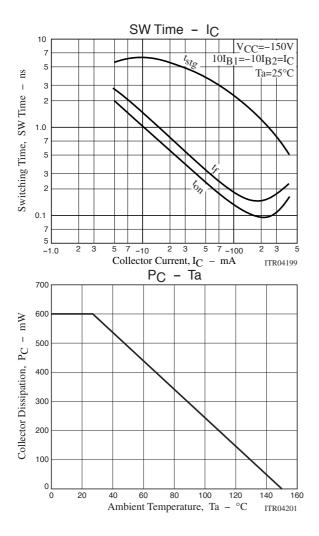
Switching Time Test Circuit

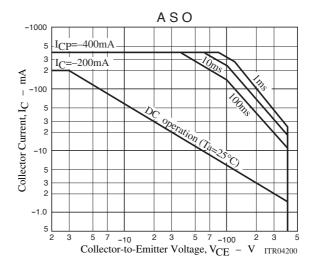


-10IB₁= 10IB₂= I_C=-50mA R_L=3k Ω , R_B=200 Ω at I_C=-50mA









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